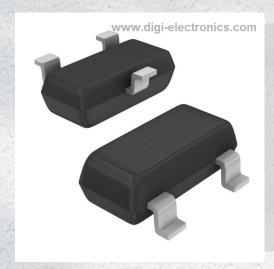


BC858BLT3G Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number BC858BLT3G-DG

Manufacturer onsemi

Manufacturer Product Number BC858BLT3G

Description TRANS PNP 30V 0.1A SOT23-3

Detailed Description Bipolar (BJT) Transistor PNP 30 V 100 mA 100MHz 3

00 mW Surface Mount SOT-23-3 (TO-236)



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

| Manufacturer Product Number: | Manufacturer: |
|--|--|
| BC858BLT3G | onsemi |
| Series: | Product Status: |
| | Active |
| Transistor Type: | Current - Collector (Ic) (Max): |
| PNP | 100 mA |
| Voltage - Collector Emitter Breakdown (Max): | Vce Saturation (Max) @ lb, Ic: |
| 30 V | 650mV @ 5mA, 100mA |
| Current - Collector Cutoff (Max): | DC Current Gain (hFE) (Min) @ Ic, Vce: |
| 15nA (ICBO) | 220 @ 2mA, 5V |
| Power - Max: | Frequency - Transition: |
| 300 mW | 100MHz |
| Operating Temperature: | Mounting Type: |
| -55°C ~ 150°C (TJ) | Surface Mount |
| Package / Case: | Supplier Device Package: |
| TO-236-3, SC-59, SOT-23-3 | SOT-23-3 (TO-236) |
| Base Product Number: | |
| BC858 | |

Environmental & Export classification

| RoHS Status: | Moisture Sensitivity Level (MSL): |
|------------------|-----------------------------------|
| ROHS3 Compliant | 1 (Unlimited) |
| REACH Status: | ECCN: |
| REACH Unaffected | EAR99 |
| HTSUS: | |
| 8541.21.0075 | |



General Purpose Transistors

PNP Silicon

BC856ALT1G Series

Features

- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise noted)

| Rating | Symbol | Value | Unit |
|--|------------------|-------------------|------|
| Collector-Emitter Voltage BC856, SBC856 BC857, SBC857 BC858, NSVBC858, BC859 | V _{CEO} | -65 -45 -30 | > |
| Collector-Base Voltage BC856, SBC856 BC857, SBC857 BC858, NSVBC858, BC859 | V _{CBO} | -80 -50 -30 | > |
| Emitter-Base Voltage | V _{EBO} | -5.0 | V |
| Collector Current - Continuous | I _C | -100 | mAdc |
| Collector Current - Peak | I _C | -200 | mAdc |

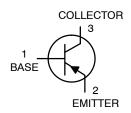
THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|--|-----------------------------------|-------------|-------------|
| Total Device Dissipation FR-5 Board, (Note 1) T _A = 25°C Derate above 25°C | P _D | 225 1.8 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 556 | °C/W |
| Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C | P _D | 300 2.4 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 417 | °C/W |
| Junction and Storage Temperature | T _J , T _{stg} | -55 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1

- 1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = $0.4 \times 0.3 \times 0.024$ in 99.5% alumina.





SOT-23 (TO-236) CASE 318 STYLE 6

MARKING DIAGRAM



xx = Device Code

xx = (Refer to page 6)

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

| Characteristic | Symbol | Min | Тур | Max | Unit |
|--|----------------------|----------------------|------------------|----------------|----------|
| OFF CHARACTERISTICS | | | | | |
| Collector – Emitter Breakdown Voltage BC856, SBC856 Series (I _C = -10 mA) BC857, SBC857 Series | V _{(BR)CEO} | -65 -45 | - - | _ _ | V |
| BC858, NSBVC858 BC859 Series | | -30 | - | - | |
| Collector – Emitter Breakdown Voltage BC856 S, SBC856eries $(I_C=-10~\mu\text{A},~V_{EB}=0)$ BC857A, SBC857A, BC857B, SBC857B Only BC858, NSVB858, BC859 Series | $V_{(BR)CES}$ | -80 -50 -30 | - - - | - - - | V |
| Collector – Base Breakdown Voltage BC856, SBC856 Series (I _C = -10 μA) BC857, SBC857 Series BC858, NSVBC858, BC859 Series | V _{(BR)CBO} | -80 -50 -30 | - - - | - - - | V |
| Emitter – Base Breakdown Voltage BC856, SBC856 Series $(I_E = -1.0 \ \mu\text{A})$ BC857, SBC857 Series BC858, NSVBC858, BC859 Series | V _{(BR)EBO} | -5.0 -5.0 -5.0 | - - - | - - - | V |
| Collector Cutoff Current ($V_{CB} = -30 \text{ V}$) ($V_{CB} = -30 \text{ V}$, $T_A = 150^{\circ}\text{C}$) | I _{CBO} | - - | - - | -15 -4.0 | nA μA |
| ON CHARACTERISTICS | | | | | |
| DC Current Gain BC856A, SBC856A, BC857A, SBC857A, BC858A $(I_C = -10~\mu\text{A}, V_{CE} = -5.0~\text{V})$ BC856B, SBC856B, BC857B, SBC856B, BC858B, NSVBC858B BC857C, SBC857C BC858C | h _{FE} | | 90 150 270 | - | - |
| $(I_C = -2.0 \text{ mA}, V_{CE} = -5.0 \text{ V})$ BC856A, SBC856A, BC857A, | | 125 | 180 | 250 | |
| SBC857A, BC858A BC856B, SBC856B, BC857B, SBC857B, BC858B, NSVBC858B, BC859B | | 220 | 290 | 475 | |
| BC857C, SBC857C, BC858C, BC859C | | 420 | 520 | 800 | |
| Collector – Emitter Saturation Voltage ($I_C = -10$ mA, $I_B = -0.5$ mA) ($I_C = -100$ mA, $I_B = -5.0$ mA) | V _{CE(sat)} | | | -0.3 -0.65 | V |
| Base – Emitter Saturation Voltage ($I_C = -10$ mA, $I_B = -0.5$ mA) ($I_C = -100$ mA, $I_B = -5.0$ mA) | V _{BE(sat)} | - - | -0.7 -0.9 | - - | V |
| Base – Emitter On Voltage ($I_C = -2.0 \text{ mA}, V_{CE} = -5.0 \text{ V}$) ($I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ V}$) | V _{BE(on)} | -0.6 - | - - | -0.75 -0.82 | V |
| SMALL-SIGNAL CHARACTERISTICS | | | | | |
| Current – Gain – Bandwidth Product (I _C = –10 mA, V _{CE} = –5.0 Vdc, f = 100 MHz) | f _T | 100 | - | - | MHz |
| Output Capacitance (V _{CB} = -10 V, f = 1.0 MHz) | C _{ob} | - | - | 4.5 | pF |
| Noise Figure $ \text{(I}_{C} = -0.2 \text{ mA, V}_{CE} = -5.0 \text{ Vdc, R}_{S} = 2.0 \text{ k}\Omega, \text{f} = 1.0 \text{ kHz, BW} = 200 \text{ Hz)} \\ \text{BC856, SBC856, BC857, SBC857, BC858, NSVBC858 Series} \\ \text{BC859 Series} $ | NF | - - | - - | 10 4.0 | dB |
| SWITCHING CHARACTERISTICS | | - | - | - | - |
| Delay Time ($V_{CC} = -3.0 \text{ Vdc}$, $I_C = -10 \text{ mA}$, $I_E = -1 \text{ mA}$) | t _d | - | 35 | - | ns |
| Rise Time ($V_{CC} = -3.0 \text{ Vdc}$, $I_C = -10 \text{ mA}$, $I_E = -1 \text{ mA}$) | t _r | _ | 25 | _ | ns |
| Storage Time ($V_{CC} = -3.0 \text{ Vdc}$, $I_C = -10 \text{ mA}$, $I_E = -1 \text{ mA}$) | t _s | _ | 310 | _ | ns |
| Fall Time ($V_{CC} = -3.0 \text{ Vdc}$, $I_C = -10 \text{ mA}$, $I_E = -1 \text{ mA}$) | t _f | _ | 40 | _ | ns |
| , 55 | | | <u> </u> | I | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

BC857/BC858/BC859/SBC857/NSVBC858

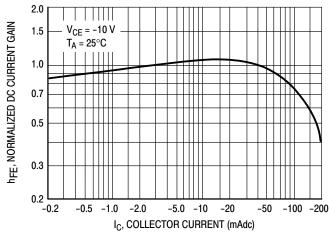


Figure 1. Normalized DC Current Gain

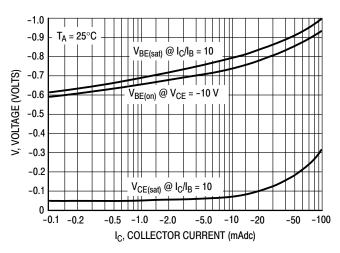


Figure 2. "Saturation" and "On" Voltages

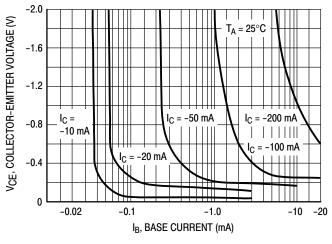


Figure 3. Collector Saturation Region

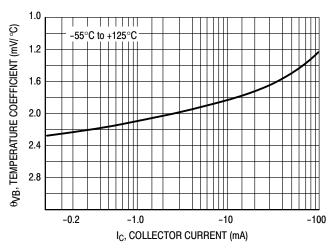


Figure 4. Base-Emitter Temperature Coefficient

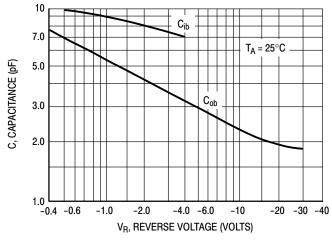


Figure 5. Capacitances

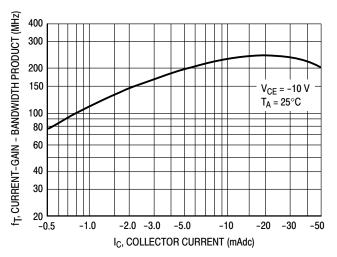


Figure 6. Current-Gain - Bandwidth Product

BC856/SBC856

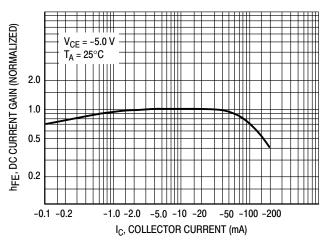


Figure 7. DC Current Gain

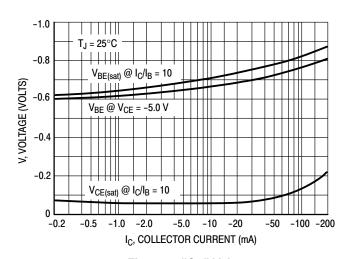


Figure 8. "On" Voltage

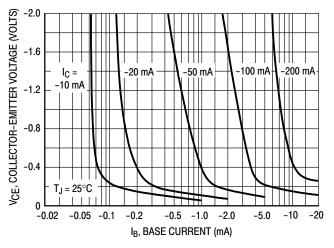


Figure 9. Collector Saturation Region

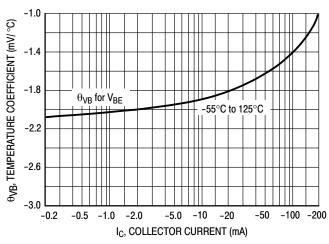


Figure 10. Base-Emitter Temperature Coefficient

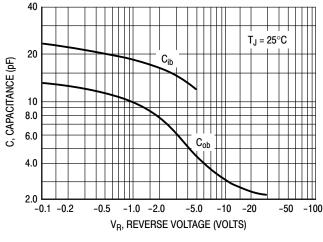


Figure 11. Capacitance

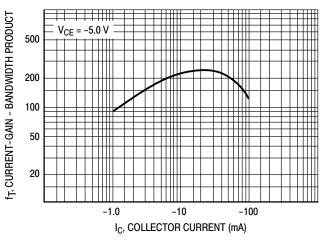


Figure 12. Current-Gain - Bandwidth Product

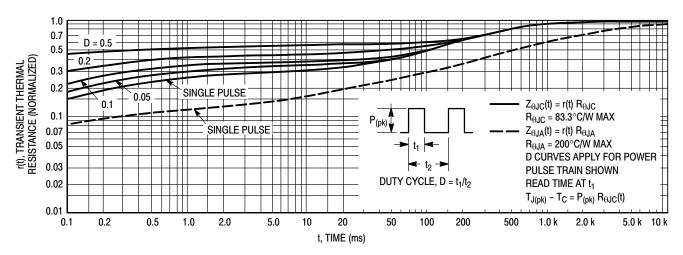


Figure 13. Thermal Response

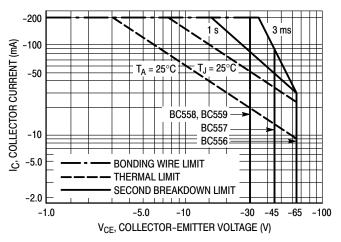


Figure 14. Active Region Safe Operating Area

The safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 14 is based upon $T_{J(pk)} = 150^{\circ}\mathrm{C}$; T_{C} or T_{A} is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^{\circ}\mathrm{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

ORDERING INFORMATION

| Device | Marking | Package | Shipping [†] |
|----------------|---------|---------------------|-----------------------|
| BC856ALT1G | 3A | SOT-23 | 3,000 / Tape & Reel |
| SBC856ALT1G* | | (Pb-Free) | |
| BC856ALT3G | | | 10,000 / Tape & Reel |
| BC856BLT1G | 3B | SOT-23 | 3,000 / Tape & Reel |
| SBC856BLT1G* | | (Pb-Free) | |
| BC856BLT3G | | | 10,000 / Tape & Reel |
| SBC856BLT3G* | | | |
| BC857ALT1G | 3E | SOT-23 | 3,000 / Tape & Reel |
| SBC857ALT1G* | | (Pb-Free) | |
| BC857BLT1G | 3F | SOT-23 | 3,000 / Tape & Reel |
| SBC857BLT1G* | | (Pb-Free) | |
| BC857BLT3G | | | 10,000 / Tape & Reel |
| NSVBC857BLT3G* | | | |
| BC857CLT1G | 3G | SOT-23 | 3,000 / Tape & Reel |
| SBC857CLT1G* | | (Pb-Free) | |
| BC857CLT3G | | | 10,000 / Tape & Reel |
| BC858ALT1G | 3J | SOT-23 (Pb-Free) | 3,000 / Tape & Reel |
| BC858BLT1G | зк | SOT-23 | |
| NSVBC858BLT1G* | | (Pb-Free) | |
| BC858BLT3G | | SOT-23 (Pb-Free) | 10,000 / Tape & Reel |
| BC858CLT1G | 3L | SOT-23 (Pb-Free) | 3,000 / Tape & Reel |
| BC858CLT3G | | SOT-23 (Pb-Free) | 10,000 / Tape & Reel |
| BC859BLT1G | 4B | SOT-23 (Pb-Free) | 3,000 / Tape & Reel |
| BC859BLT3G | | SOT-23 (Pb-Free) | 10,000 / Tape & Reel |
| BC859CLT1G | 4C | SOT-23 (Pb-Free) | 3,000 / Tape & Reel |
| BC859CLT3G | | SOT-23 (Pb-Free) | 10,000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.



MECHANICAL CASE OUTLINE

MILLIMETERS

MIN

0.89

0.01

0.37

0.08

2.80

1.20

1.78

0.30

0.35

2.10

O°

NOM

1.00

0.06

0.44

0.14

2.90

1.30

1.90

0.43

0.54

2.40

PACKAGE DIMENSIONS



SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318 ISSUE AU**

DATE 14 AUG 2024

MAX

1.11

0.10

0.50

0.20

3.04

1.40

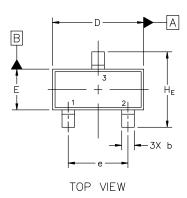
2.04

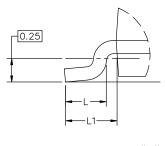
0.55

0.69

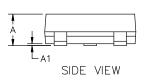
2.64

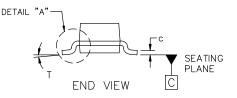
10°

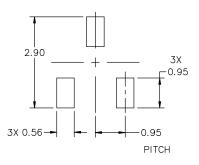




DETAIL "A" Scale 3:1







NOTES:

DIM

Α

Α1

b

С

D

Ε

е L

L1

HE

Τ

- DIMENSIONING AND TOLERANCING 1.
- PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE
- BASE MATERIAL.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

SOT-23 (TO-236) 2.90x1.30x1.00 1.90P CASE 318 ISSUE AU

DATE 14 AUG 2024

| STYLE 1 THRU 5: CANCELLED | STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR | STYLE 7: STYLE 8: PIN 1. EMITTER PIN 1. ANOD 2. BASE 2. NO CC 3. COLLECTOR 3. CATHO | ONNECTION | |
|---|---|---|-----------------------|-------|
| STYLE 9: PIN 1. ANODE 2. ANODE 3. CATHODE | STYLE 10: PIN 1. DRAIN 2. SOURCE 3. GATE | STYLE 11: STYLE 12: PIN 1. ANODE PIN 1. CATHO 2. CATHODE 2. CATHO 3. CATHODE-ANODE 3. ANODO | ODE 2. DRAIN 2. GATE | |
| STYLE 15: PIN 1. GATE 2. CATHODE 3. ANODE | STYLE 16: PIN 1. ANODE 2. CATHODE 3. CATHODE | STYLE 17: STYLE 18: PIN 1. NO CONNECTION PIN 1. NO CO 2. ANODE 2. CATHO 3. CATHODE 3. ANODO | ODE 2. ANODE 2. ANODE | |
| STYLE 21: PIN 1. GATE 2. SOURCE 3. DRAIN | STYLE 22: PIN 1. RETURN 2. OUTPUT 3. INPUT | STYLE 23: STYLE 24: PIN 1. ANODE PIN 1. GATE 2. ANODE 2. DRAIN 3. CATHODE 3. SOURCE | | CTION |
| STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE | STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE | | | |

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ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales



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